

Features

- $I_{F(AV)}$ 3A
- V_{RRM} 50V-1000V
- High surge current capability
- Polarity: Color band denotes cathode

Applications

- Rectifier

Marking

- S3X

X : From A To M



SMAF top view



Schematic diagram



Halogen-Free

Limiting Values (Absolute Maximum Rating)

Symbol	Item	Conditions	S3							Unit
			AF	BF	DF	GF	JF	KF	MF	
V_{RRM}	Repetitive Peak Reverse Voltage		50	100	200	400	600	800	1000	V
V_{RMS}	Maximum RMS Voltage		35	70	140	280	420	560	700	V
$I_{F(AV)}$	Average Rectified Output Current	60Hz Half-sine wave, Resistance load, $T_L=100^{\circ}C$	3.0							A
I_{FSM}	Surge(Non-repetitive)Forward Current	60Hz Half-sine wave, 1 cycle, $T_a=25^{\circ}C$	90							A
T_J, T_{STG}	Operating and Storage Temperature Range		-55~ +150							$^{\circ}C$

Electrical Characteristics ($T_a=25^{\circ}C$ Unless otherwise specified)

Symbol	Item	Condition	S3							Unit
			AF	BF	DF	GF	JF	KF	MF	
V _F	Peak Forward Voltage	I _F =3.0A	1.1							V
I _{RRM1}	Peak Reverse Current	V _{RM} =V _{RRM} T _a =25℃	5							μA
I _{RRM2}		V _{RM} =V _{RRM} T _a =100℃	50							
R _{θJ-A}	Thermal Resistance	Between junction and ambient	88							℃/W
C _J	Typical junction capacitance per diode	Measured at 1.0MHz and applied reverse voltage of 4.0 volts	15							pF

Typical Operating Characteristics

FIG.1: FORWARD CURRENT DERATING CURVE

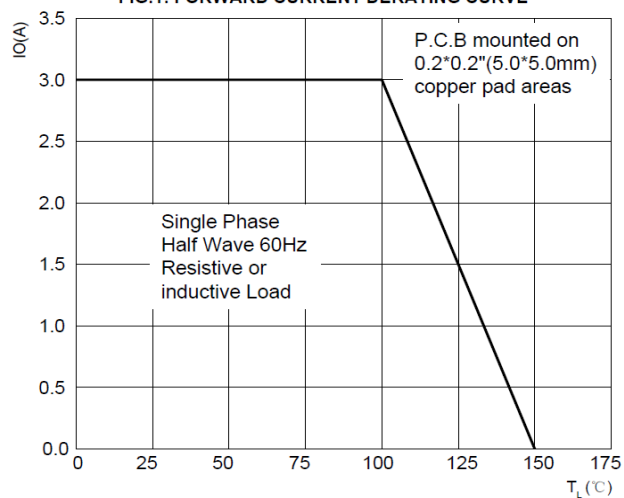


FIG2: Surge Forward Current Capability

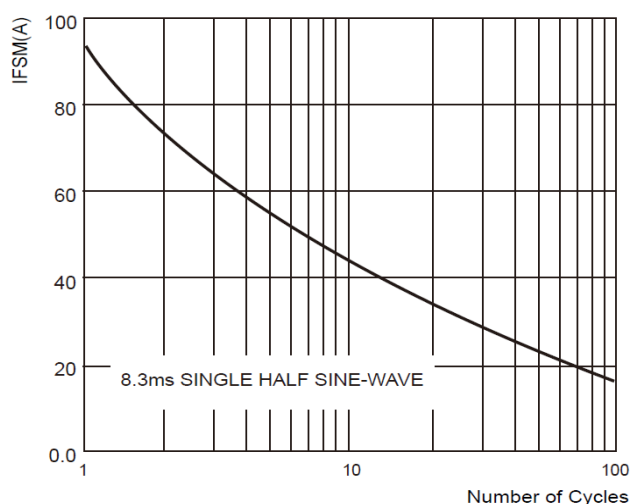


FIG.3: TYPICAL FORWARD CHARACTERISTICS

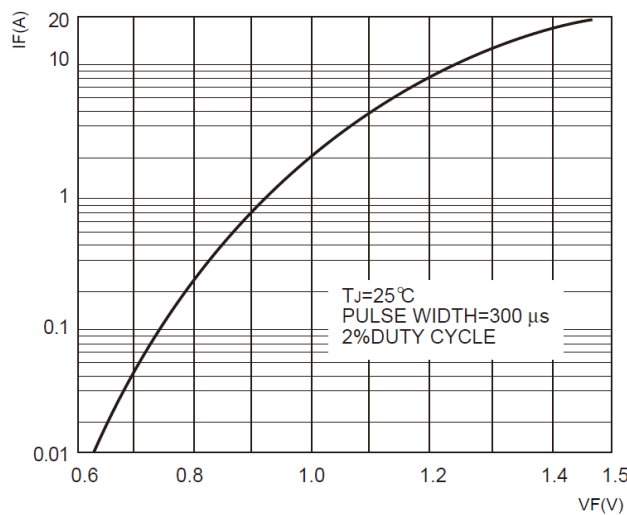
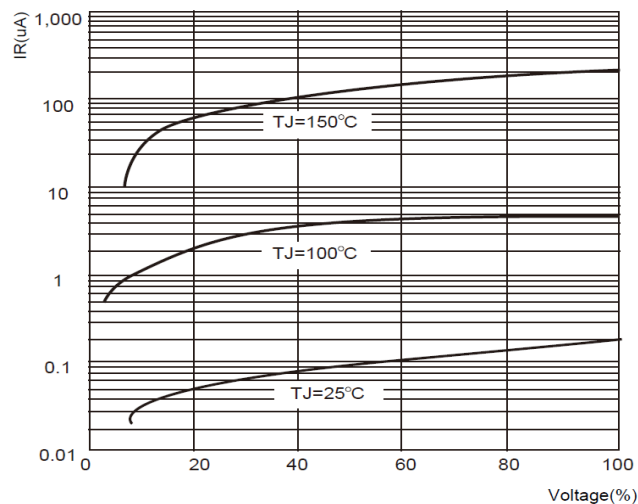
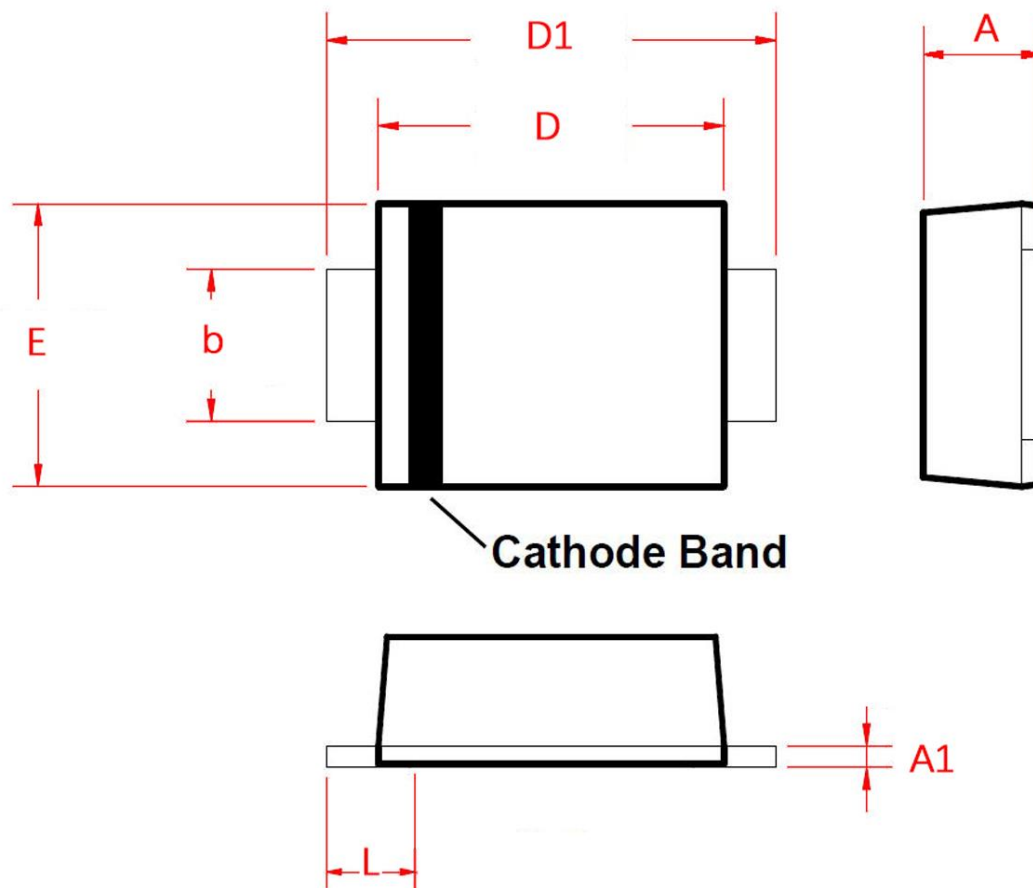


FIG.4 : TYPICAL REVERSE CHARACTERISTICS



SMAF Package information



Symbol	Dimensions in Millimeters(mm)		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.200	0.035	0.047
A1	0.120	0.180	0.005	0.007
b	1.300	1.600	0.051	0.063
D	3.300	3.700	0.130	0.146
D1	4.400	4.900	0.173	0.193
E	2.400	2.700	0.094	0.106
L	0.800	1.300	0.031	0.051